# NSN 5961-01-165-0590

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# **Inclosure Material:**

Metal

**Overall Length:** 

0.210 inches

# Terminal Length:

1.500 inches

# **Overall Diameter:**

0.195 inches

### **Internal Configuration:**

Junction contact-double emitter

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18

# **Mounting Method:**

Terminal

### Terminal Circle Diameter:

# 0.100 inches

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, emitter-to-base, collector open and 50.0 breakdown voltage, emitter to collector, base open and 50.0

breakdown voltage, collector-to-base, emitter open

# **Current Rating Per Characteristic:**

10.00 nanoamperes zero-gate-voltage source current preset

# Transfer Ratio:

1.5 static forward current transfer ratio, common-emitter

# **Special Features:**

Junction pattern arrangement: pnp

# **Terminal Type And Quantity:**

4 uninsulated wire lead

# Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

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